

**Voltage Detector IC Series** 

# Low Voltage Free Delay Time Setting CMOS Voltage Detector IC Series

### BU42xx series BU43xx series

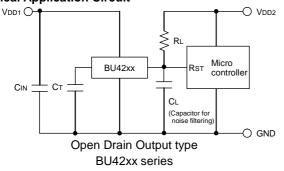
#### General Description

ROHM's BU42xx and BU43xx series are CMOS Voltage Detector ICs with adjustable output delay. It is a high-accuracy, low current consumption Voltage Detector IC series with a built-in delay circuit. The lineup was established with two output types (Nch open drain and CMOS output) and detection voltages range from 0.9V to 4.8V in increments of 0.1V, so that the series may be selected according to application.

#### Features

- Delay Time Controlled by external Capacitor
- Two output types (Nch open drain and CMOS output)
- Ultra-low current consumption
- Wide operating temperature range
- Very small and low height package
- Package SSOP5 and SOP4 is similar to SOT-23-5 and SC-82 respectively (JEDEC)

#### ●Typical Application Circuit



#### Key Specifications

■ Detection voltage: 0.9V to 4.8V (Typ.)

0.1V steps

High accuracy detection voltage: ±1.0%
 Ultra-low current consumption: 0.55µA (Typ.)
 Operating temperature range: -40°C to +125°C

Package

SSOP5:

SOP4:



2.90mm x 2.80mm x 1.25mm

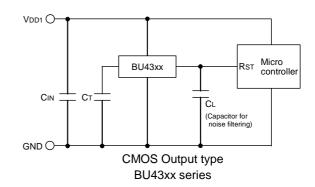


1.60mm x 1.60mm x 0.60mm

VSOF5:

#### Applications

Circuits using microcontrollers or logic circuits that require a reset.

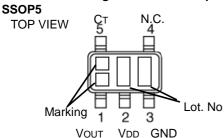


VSOF5

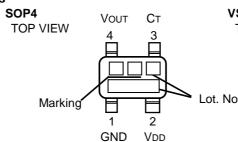
TOP VIEW

Marking

#### Connection Diagram & Pin Descriptions



| PIN<br>No. | Symbol | Function  |  |  |  |
|------------|--------|---|--|--|--|
| 1          | Vout   | Reset output  |  |  |  |
| 2          | Vdd    | Power supply voltage                                |  |  |  |
| 3          | GND    | GND   |  |  |  |
| 4          | N.C.   | Unconnected terminal                                |  |  |  |
| 5          | Ст     | Capacitor connection terminal for output delay time |  |  |  |



|            |        | ****  |  |  |
|------------|--------|---|--|--|
| PIN<br>No. | Symbol | Function  |  |  |
| 1          | GND    | GND   |  |  |
| 2          | Vdd    | Power supply voltage                                |  |  |
| 3          | Ст     | Capacitor connection terminal for output delay time |  |  |
| 4          | Vout   | Reset output  |  |  |
|            |        | _   |  |  |

| =          |        |   |
|------------|--------|---|
| PIN<br>No. | Symbol | Function  |
| 1          | Vout   | Reset output  |
| 2          | SUB    | Substrate*  |
| 3          | Ст     | Capacitor connection terminal for output delay time |
| 4          | Vdd    | Power supply voltage                                |
| 5          | GND    | GND   |

GND VDD

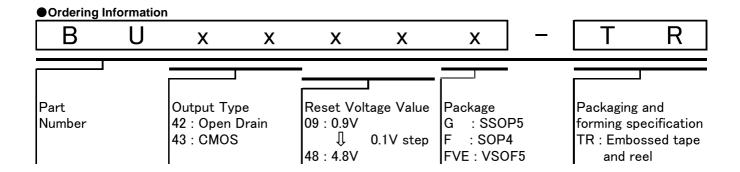
1 2 3

VOUT SUB CT

Lot. No

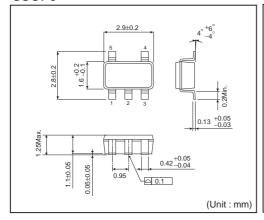
\*Connect the substrate to VDD

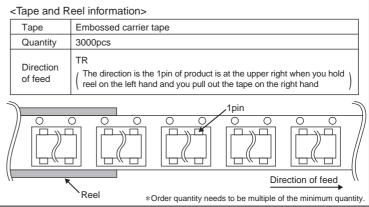
OProduct structure: Silicon monolithic integrated circuit OThis product is not designed for protection against radioactive rays



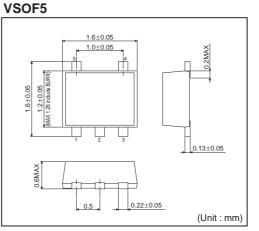
#### SSOP5

SOP4





0.05 0.13 +0.05 s  $0.05\pm0.05$ □ 0.1 S 0.32 +0.05 (Unit:mm)



#### **●**Lineup

| Output Type       | Output Type Open Drain CMOS |             |                     | CMOS   |  |
|-------------------|-----------------------------|-------------|---------------------|--------|--|
| Detection Voltage | Marking                     | Part Number | Marking Part Number |        |  |
| 4.8V              | ZR                          | BU4248      | 1H                  | BU4348 |  |
| 4.7V              | ZQ                          | BU4247      | 1G                  | BU4347 |  |
| 4.6V              | ZP                          | BU4246      | 1F                  | BU4346 |  |
| 4.5V              | ZN                          | BU4245      | 1E                  | BU4345 |  |
| 4.4V              | ZM                          | BU4244      | 1D                  | BU4344 |  |
| 4.3V              | ZL                          | BU4243      | 1C                  | BU4343 |  |
| 4.2V              | ZK                          | BU4242      | 1B                  | BU4342 |  |
| 4.1V              | ZJ                          | BU4241      | 1A                  | BU4341 |  |
| 4.0V              | ZH                          | BU4240      | 0Z                  | BU4340 |  |
| 3.9V              | ZG                          | BU4239      | 0Y                  | BU4339 |  |
| 3.8V              | ZF                          | BU4238      | 0X                  | BU4338 |  |
| 3.7V              | ZE                          | BU4237      | OW                  | BU4337 |  |
| 3.6V              | ZD                          | BU4236      | 0V                  | BU4336 |  |
| 3.5V              | ZC                          | BU4235      | 0U                  | BU4335 |  |
| 3.4V              | ZB                          | BU4234      | 0T                  | BU4334 |  |
| 3.3V              | ZA                          | BU4233      | 0S                  | BU4333 |  |
| 3.2V              | YZ                          | BU4232      | 0R                  | BU4332 |  |
| 3.1V              | YY                          | BU4231      | 0Q                  | BU4331 |  |
| 3.0V              | YX                          | BU4230      | 0P                  | BU4330 |  |
| 2.9V              | YW                          | BU4229      | 0N                  | BU4329 |  |
| 2.8V              | YV                          | BU4228      | OM                  | BU4328 |  |
| 2.7V              | YU                          | BU4227      | 0L                  | BU4327 |  |
| 2.6V              | YT                          | BU4226      | 0K                  | BU4326 |  |
| 2.5V              | YS                          | BU4225      | 0J                  | BU4325 |  |
| 2.4V              | YR                          | BU4224      | 0H                  | BU4324 |  |
| 2.3V              | YQ                          | BU4223      | 0G                  | BU4323 |  |
| 2.2V              | YP                          | BU4222      | 0F                  | BU4322 |  |
| 2.1V              | YN                          | BU4221      | 0E                  | BU4321 |  |
| 2.0V              | YM                          | BU4220      | 0D                  | BU4320 |  |
| 1.9V              | YL                          | BU4219      | 0C                  | BU4319 |  |
| 1.8V              | YK                          | BU4218      | 0B                  | BU4318 |  |
| 1.7V              | YJ                          | BU4217      | 0A                  | BU4317 |  |
| 1.6V              | YH                          | BU4216      | ZZ                  | BU4316 |  |
| 1.5V              | YG                          | BU4215      | ZY                  | BU4315 |  |
| 1.4V              | YF                          | BU4214      | ZX                  | BU4314 |  |
| 1.3V              | YE                          | BU4213      | ZW                  | BU4313 |  |
| 1.2V              | YD                          | BU4212      | ZV                  | BU4312 |  |
| 1.1V              | YC                          | BU4211      | ZU                  | BU4311 |  |
| 1.0V              | YB                          | BU4210      | ZT                  | BU4310 |  |
| 0.9V              | YA                          | BU4209      | ZS                  | BU4309 |  |

#### ● Absolute Maximum Ratings

| F                           | Parameter             | Symbol | Limit              | Unit |  |
|-----------------------------|-----------------------|--------|--------------------|------|--|
| Power Supply Voltage        |                       | Vdd    | -0.3 to +7         | V    |  |
| Output Valtage              | Nch Open Drain Output | Vout   | GND-0.3 to +7      | V    |  |
| Output Voltage              | CMOS Output           | Vout   | GND-0.3 to VDD+0.3 | V    |  |
| Output Current              |                       | lo     | 70                 | mA   |  |
|                             | SSOP5(SOT-23-5) *1*4  |        | 540                |      |  |
| Power<br>Dissipation        | SOP4(SC-82) *2*4      | Pd     | 400                | mW   |  |
|                             | VSOF5 *3*4            |        | 210                |      |  |
| Operation Temperature Range |                       | Topt   | -40 to +125        | °C   |  |
| Ambient Storage T           | emperature            | Tstg   | -55 to +125        | °C   |  |

<sup>\*1</sup> Reduced by 5.4mW/°C when used over 25°C.

● Electrical Characteristics (Unless Otherwise Specified Ta=-25 to 125°C)

| Parameter                    | Symbol            | Symbol Condition                            |   | Limit                         |                      |                               | Unit  |
|------------------------------|-------------------|---|---|-------------------------------|----------------------|-------------------------------|-------|
| i didilletel                 | Symbol            | •   | Condition                                 |                               |                      | Max.                          | Oilit |
|                              |                   | VDD=H→L, Ta=25°C, RL=470kΩ                  |   | V <sub>DET</sub> (T)<br>×0.99 | V <sub>DET</sub> (T) | V <sub>DET</sub> (T)<br>×1.01 |       |
|                              |                   |   | Ta=+25°C                                  | 1.782                         | 1.8                  | 1.818                         |       |
|                              |                   | VDET=1.8V                                   | Ta=-40°C to 85°C                          | 1.741                         | -                    | 1.860                         |       |
|                              |                   |   | Ta=85°C to 125°C                          | 1.718                         | -                    | 1.883                         |       |
|                              |                   |   | Ta=+25°C                                  | 2.475                         | 2.5                  | 2.525                         |       |
|                              |                   | VDET=2.5V                                   | Ta=-40°C to 85°C                          | 2.418                         | -                    | 2.584                         |       |
|                              |                   |   | Ta=85°C to 125°C                          | 2.386                         | -                    | 2.615                         | 1     |
| Detection Voltage            | $V_{DET}$         |   | Ta=+25°C                                  | 2.970                         | 3.0                  | 3.030                         | V     |
|                              | 52.               | VDET=3.0V                                   | Ta=-40°C to 85°C                          | 2.901                         | -                    | 3.100                         |       |
|                              |                   |   | Ta=85°C to 125°C                          | 2.864                         | _                    | 3.139                         |       |
|                              |                   |   | Ta=+25°C                                  | 3.267                         | 3.3                  | 3.333                         |       |
|                              |                   | VDET=3.3V                                   | Ta=-40°C to 85°C                          | 3.191                         | -                    | 3.410                         |       |
|                              |                   | VDL1=3.5V                                   | Ta=85°C to 125°C                          | 3.150                         | _                    | 3.452                         |       |
|                              |                   |   | Ta=+25°C                                  | 4.158                         | 4.2                  | 4.242                         |       |
|                              |                   | \/DET_4.0\/                                 | Ta=-40°C to 85°C                          | 4.061                         | 4.2                  | 4.341                         |       |
|                              |                   | VDET=4.2V                                   | Ta=85°C to 125°C                          | 4.001                         | -                    | 4.394                         |       |
|                              |                   |   | V <sub>DET</sub> =0.9 to 1.3V             | 4.009                         | 0.15                 | 0.88                          |       |
|                              |                   |   | V <sub>DET</sub> = 1.4 TO 2.1V            | -                             | 0.10                 | 1.05                          |       |
|                              |                   |   | V <sub>DET</sub> =2.2 TO 2.7V             | -                             | 0.25                 | 1.23                          |       |
| Circuit Current when ON      | I <sub>DD</sub> 1 | VDD=VDET-0.2V                               | V <sub>DET</sub> =2.8 to 3.3V             | -                             | 0.30                 | 1.40                          | μA    |
|                              |                   |   | V <sub>DET</sub> =3.4 to 4.2V             | -                             | 0.35                 | 1.58                          | μΑ    |
|                              |                   |   | $V_{DET} = 4.3 \text{ to } 4.8 \text{V}$  | -                             | 0.40                 | 1.75                          |       |
|                              |                   |   | $V_{DET} = 0.9 \text{ TO } 1.3 \text{V}$  | -                             | 0.30                 | 1.40                          |       |
|                              |                   |   | $V_{DET} = 1.4 \text{ TO } 2.1 \text{ V}$ | -                             | 0.35                 | 1.58                          |       |
| Circuit Current when OFF     | I <sub>DD</sub> 2 | VDD=VDET+2.0V                               | $V_{DET} = 2.2 \text{ to } 2.7 \text{V}$  | -                             | 0.40                 | 1.75                          |       |
| onean carrent when or r      | שטטי              | VDD=VDE1+2.0V                               | $V_{DET} = 2.8 \text{ to } 3.3 \text{V}$  | -                             | 0.45                 | 1.93                          |       |
|                              |                   |   | $V_{DET} = 3.4 \text{ to } 4.2 \text{V}$  | -                             | 0.50                 | 2.10                          |       |
|                              |                   |   | $V_{DET} = 4.3 \text{ to } 4.8 \text{V}$  | -                             | 0.55                 | 2.28                          |       |
| Operating Voltage Range      | V <sub>OPL</sub>  | VoL≤0.4V, Ta=25 to 125°C, RL=470kΩ          |   | 0.70                          | -                    | -                             | V     |
| Operating voltage realige    |                   | VoL≤0.4V, Ta=-40 to 25°C, RL=470kΩ          |   | 0.90                          | -                    | -                             | V     |
| 'High' Output Voltage (Pch)  | Voн               | VDD=4.8V, Isource=1.7 mA, VDET=0.9V to 3.9V |   | VDD-0.5                       | -                    | -                             | V     |
| I light Output voltage (PCH) |                   | VDD=6.0V, Isource=2.0 mA, VDET=4.0V to 4.8V |   | VDD-0.5                       | _                    | -                             | V     |
|                              |                   | VDD=0.85V, ISINK = 20 μA                    |   | -                             | -                    | 0.05                          | V     |
| 'Low' Output Voltage (Nch)   | $V_{OL}$          | VDD=1.5V, ISINK = 1 MA, VDET=1.7 to 4.8V    |   | -                             | -                    | 0.5                           | '     |
| -                            |                   | VDD=2.4V, ISINK = 3.6 mA, VDET=2.7 to 4.8V  |   | -                             | -                    | 0.5                           | V     |

<sup>\*1:</sup> Design Guarantee. (Outgoing inspection is not done on all products.)

V<sub>DET</sub>(T): Standard Detection Voltage (0.9V to 4.8V, 0.1V step)

R<sub>L</sub>: Pull-up resistor to be connected between VouT and power supply.

<sup>\*2</sup> Reduced by 4.0mW/°C when used over 25°C.

<sup>\*3</sup> Reduced by 2.1mW/°C when used over 25°C.

<sup>\*4</sup> When mounted on ROHM standard circuit board (70mm×70mm×1.6mm, glass epoxy board).

● Electrical Characteristics (Unless Otherwise Specified Ta=-25 to 125°C) - continued

| Doromotor                                    | Cumbal               | Condition  |           | Limit                             |                                  |                           | I Imia                                |
|--|----------------------|--|-----------|-----------------------------------|----------------------------------|---------------------------|---------------------------------------|
| Parameter                                    | Symbol               |  |           | Min.                              | Тур.                             | Max.                      | Unit                                  |
| Look Cumont when OFF                         |                      | VDD=VDS=7V Ta=-40 to 85°C                                      | ;         | -                                 | 0                                | 0.1                       |                                       |
| Leak Current when OFF                        | l <sub>leak</sub>    | VDD=VDS=7V Ta=85 to 125°0                                      | 0         | -                                 | 0                                | 1                         | μA                                    |
| CT pin Threshold Voltage                     | V <sub>CTH</sub>     | $V_{DD}=V_{DET}\times1.1$ , $V_{DET}=0.9$ to 2. $R_{L}=470$ kΩ |           | V <sub>DD</sub><br>×0.35          | V <sub>DD</sub><br>×0.45         | V <sub>DD</sub><br>×0.55  | V                                     |
| CT pili Tilleshold vollage                   | VCIH                 | RL= $470k\Omega$ ×0.40 ×0.5                                    |           | V <sub>DD</sub><br>×0.50          | V <sub>DD</sub><br><b>×</b> 0.60 | v                         |                                       |
| Output Delay Resistance                      | R <sub>CT</sub>      | VDD=VDET×1.1 VCT=0.5V T  | a=25°C *1 | 9                                 | 10                               | 11                        | ΜΩ                                    |
| CT pin Output Current                        | 1                    | VCT=0.1V VDD=0.85V   |           | 5                                 | 40                               | -                         |                                       |
| CT pill Output Cullelit                      | I <sub>CT</sub>      | VCT=0.5V VDD=1.5V VDET=1.7 to 4.8V                             |           | 200                               | 400                              | -                         | μA                                    |
| Detection Voltage<br>Temperature coefficient | V <sub>DET</sub> /ΔT | Ta=-40°C to 125°C  |           | -                                 | ±30                              | -                         | ppm/°C                                |
| Hysteresis Voltage                           |                      | VDD=L→H→L  | VDET≤1.0V | V <sub>DET</sub><br><b>×</b> 0.03 | V <sub>DET</sub><br>×0.05        | V <sub>DET</sub><br>×0.08 | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
|  | ΔVDET                | Ta=-40 to 125°C<br>RL=470kΩ                                    | VDET≥1.1V | V <sub>DET</sub><br>×0.03         | V <sub>DET</sub><br>×0.05        | V <sub>DET</sub><br>×0.07 | V                                     |

<sup>\*1:</sup> Design Guarantee. (Outgoing inspection is not done on all products.)

V<sub>DET</sub>(T): Standard Detection Voltage (0.9V to 4.8V, 0.1V step)

R<sub>L</sub>: Pull-up resistor to be connected between Vout and power supply.

#### Block Diagrams

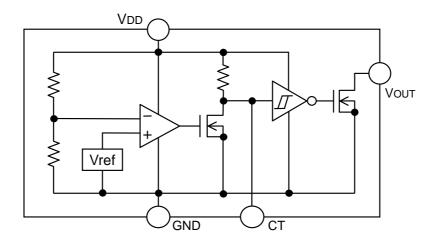


Fig.1 BU42xx Series

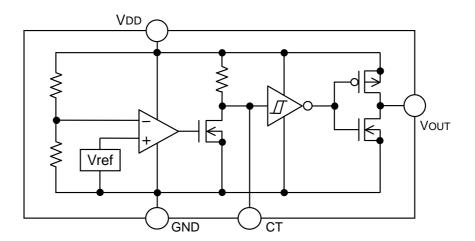


Fig.2 BU43xx Series

#### **●**Typical Performance Curves

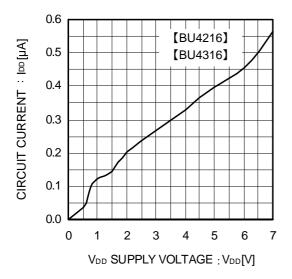


Fig.3 Circuit Current

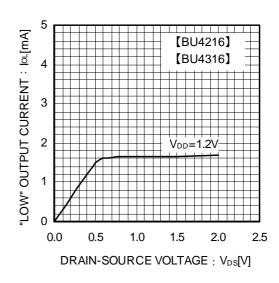


Fig.4 "LOW" Output Current

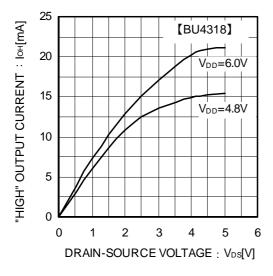


Fig.5 "High" Output Current

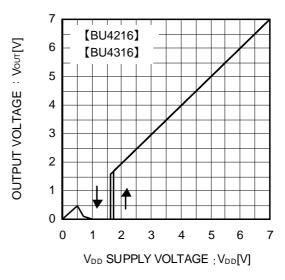


Fig.6 I/O Characteristics

#### ● Typical Performance Curves - continued

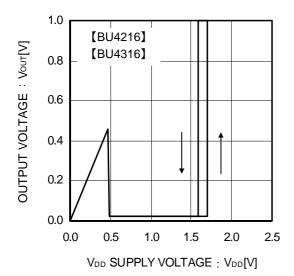


Fig.7 Operating Limit Voltage

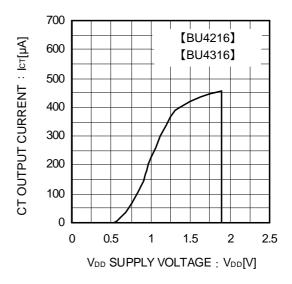


Fig.8 CT Terminal Current

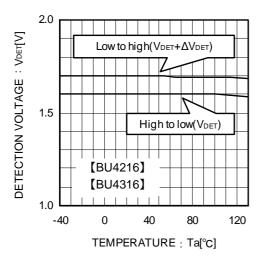


Fig.9 Detecting Voltage Release Voltage

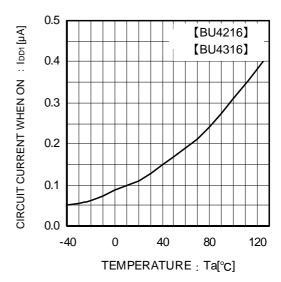


Fig.10 Circuit Current when ON

#### ● Typical Performance Curves - continued

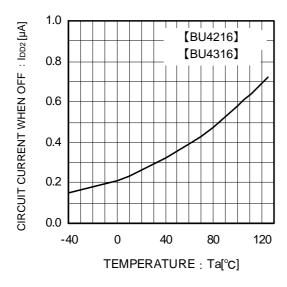


Fig.11 Circuit Current when OFF

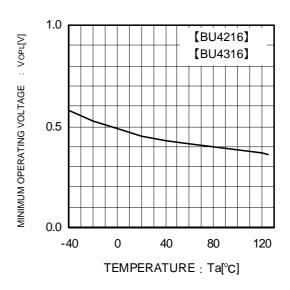


Fig.12 Operating Limit Voltage

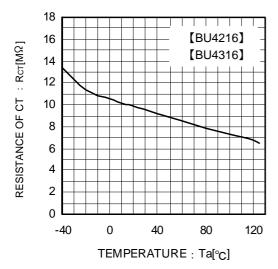


Fig.13 C<sub>T</sub> Terminal Circuit Resistance

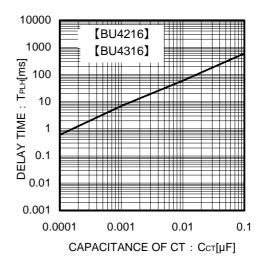


Fig.14 Delay Time (t<sub>PLH</sub>) and C<sub>T</sub> Terminal External Capacitance

#### Application Information

#### **Explanation of Operation**

For both the open drain type (Fig.15) and the CMOS output type (Fig.16), the detection and release voltages are used as threshold voltages. When the voltage applied to the VDD pins reaches the applicable threshold voltage, the VouT terminal voltage switches from either "High" to "Low" or from "Low" to "High". BU42xx and BU43xx series have delay time function which set tplh (Output "Low"->"High") using an external capacitor (CCT). Because the BU42xx series uses an open drain output type, it is necessary to connect a pull-up resistor to VDD or another power supply if needed [The output "High" voltage (VOUT) in this case becomes VDD or the voltage of the other power supply].

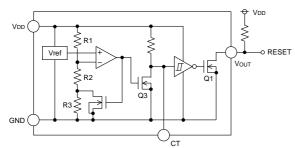


Fig.15 (BU42xx series Internal Block Diagram)

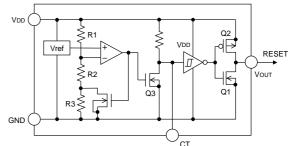


Fig.16 (BU43xx type Internal Block Diagram)

#### **Setting of Detector Delay Time**

The delay time of this detector IC can be set at the rise of VDD by the capacitor connected to C<sub>T</sub> terminal.

Delay time at the rise of VDD  $t_{PLH}$ :Time until when VouT rises to 1/2 of VDD after VDD rises up and beyond the release  $voltage(V_{DET} + \Delta V_{DET})$ 

$$T_{PLH} = -1 \times C_{CT} \times R_{CT} \times In \left( \frac{V_{DD} - V_{CTH}}{V_{DD}} \right)$$

C<sub>CT</sub>: C<sub>T</sub> pin Externally Attached Capacitance V<sub>CTH</sub>: C<sub>T</sub> pin Threshold Voltage(P.3 V<sub>CTH</sub> refer.)

R<sub>CT</sub>: C<sub>T</sub> pin Internal Impedance(P.3 R<sub>CT</sub> refer.) In: Natural Logarithm

#### Reference Data of Falling Time (t<sub>PHL</sub>) Output

Examples of Falling Time (tpHi) Output

| - | - Admpide of Falling Time (IPAL) | , Oatpat              |
|---|----------------------------------|-----------------------|
|   | Part Number                      | t <sub>PHL</sub> [µs] |
|   | BU4245                           | 275.7                 |
|   | BU4345                           | 359.3                 |

<sup>\*</sup> This data is for reference only.

The figures will vary with the application, so please confirm the actual operating conditions before use.

#### **Timing Waveforms**

Example: The following shows the relationship between the input voltage VDD, the C<sub>T</sub> Terminal Voltage VCT and the output voltage VOUT when the input power supply voltage VDD is made to sweep up and sweep down (The circuits are shown in Fig.15 and 16).

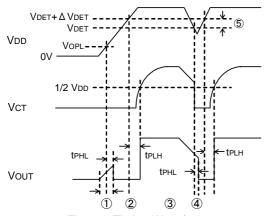


Fig.17 Timing Waveforms

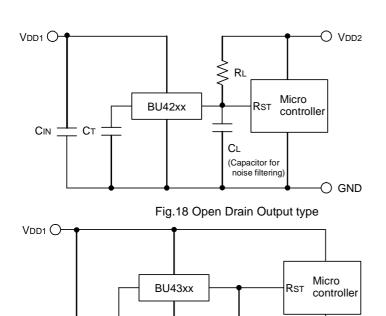
- ① When the power supply is turned on, the output is unstable from after over the operating limit voltage (VOPL) until tPHL. Therefore, it is possible that the reset signal is not outputted when the rise time of VDD is faster than tPHL.
- ② When VDD is greater than VOPL but less than the reset release voltage (VDET+ $\Delta$ VDET), the CT terminal (VCT) and output (VOUT) voltages will switch to L.
- ③ If VDD exceeds the reset release voltage (VDET+VDET), then VOUT switches from L to H (with a delay to the CT terminal).
- ④ If VDD drops below the detection voltage (VDET) when the power supply is powered down or when there is a power supply fluctuation, VOUT switches to L (with a delay of tPHL).
- (5) The potential difference between the detection voltage and the release voltage is known as the hysteresis width (VDET). The system is designed such that the output does not toggle with power supply fluctuations within this hysteresis width, preventing malfunctions due to noise.

#### Circuit Applications

Ст

GND C

1) Examples of common power supply detection reset circuits



(Capacitor for

Fig.19 CMOS Output type

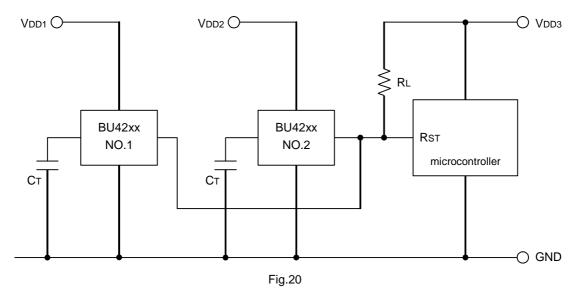
Application examples of BU42xx series (Open Drain output type) and BU43xx series (CMOS output type) are shown below.

CASE1: Power supply of microcontroller (VDD2) differs from the power supply of the reset detection (VDD1). Use an open drain output Type (BU42xx series) device with a load resistance  $R_L$  as shown Fig.18.

CASE2: Power supply of microcontroller ( $V_{DD1}$ ) is the same as the power supply of the reset detection ( $V_{DD1}$ ). Use a CMOS output type (BU43xx series) device or an open drain output type (BU42xx series) device with a pull up resistor between the output and  $V_{DD1}$ .

When a capacitance  $C_L$  for noise filtering is connected to VouT pin (the reset signal input terminal of the microcontroller), please take into account the waveform of the rise and fall time of the output voltage (VouT).

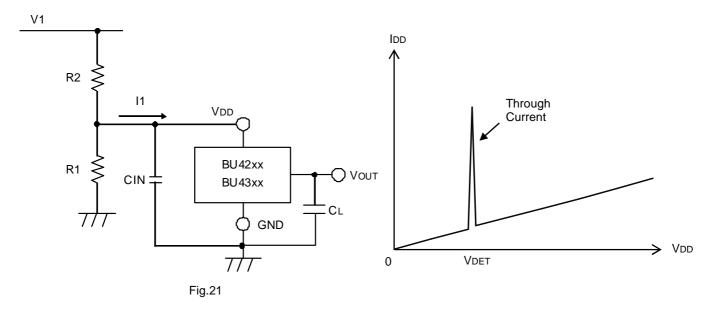
2) The following is an example of a circuit application in which an OR connection between two types of detection voltage resets the microcontroller.



To reset the microcontroller when many independent power supplies are used in the system, OR connect an open drain output type (BU42xx series) to the microcontroller's input with pull-up resistor to the supply voltage of the microcontroller (V<sub>DD3</sub>) as shown in Fig. 20. By pulling-up to V<sub>DD3</sub>, output "High" voltage of micro-controller power supply is possible.

- 3) Examples of the power supply with resistor dividers
  - In applications wherein the power supply input terminal (VDD) of an IC has resistor dividers, it is possible that an in-rush current will momentarily flow into the circuit when the output logic switches, resulting in malfunctions (such as output oscillations).

(In-rush current is a current that momentarily flows from the power supply (VDD) to ground (GND) when the output level switches from "High" to "Low" or vice versa.)



A voltage drop [in-rush current (I1)]  $\times$  [input resistor (R2)] is caused by the in-rush current, and causes the input voltage to drop when the output switches from "Low" to "High". When the input voltage decreases and falls below the detection voltage, the output voltage switches from "High" to "Low". At this time, the in-rush current stops flowing through output "Low", and the voltage drop is reduced. As a result, the output switches from "Low" to "High", which again causes the in-rush current to flow and the voltage to drop. This operation repeats and will result to oscillation.

Consider the use of BD52xx when the power supply input has resistor dividers.

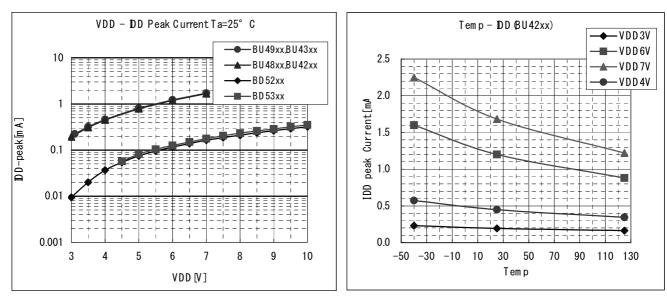


Fig.22 Current Consumption vs. Power Supply Voltage

<sup>\*</sup> This data is for reference only.

The figures will vary with the application, so please confirm the actual operating conditions before use.

#### Operational Notes

#### 1) Absolute maximum ratings

Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

#### 2) Ground Voltage

The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

#### 3) Recommended operating conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 4) Bypass Capacitor for Noise Rejection

To help reject noise, put a 1µF capacitor between VDD pin and GND and 1000pF capacitor between VOUT pin and GND. Be careful when using extremely big capacitor as transient response will be affected.

#### 5) Short between pins and mounting errors

Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

#### 6) Operation under strong electromagnetic field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

- 7) The V<sub>DD</sub> line impedance might cause oscillation because of the detection current.
- 8) A V<sub>DD</sub> to GND capacitor (as close connection as possible) should be used in high V<sub>DD</sub> line impedance condition.
- 9) Lower than the mininum input voltage puts the VouT in high impedance state, and it must be VDD in pull up (VDD) condition.

#### 10) External parameters

The case of needless "Delay Time", recommended to insert more  $470k\Omega$  resister between VDD and CT. The recommended value of  $R_L$  Resistor is over  $50k\Omega$  to  $1M\Omega$  for  $V_{DET}=1.5V$  to 4.8V, and over  $100k\Omega$  to  $1M\Omega$  for  $V_{DET}=0.9V$  to 1.4V. The recommended value of  $C_T$  Capacitor is over 100pF to  $0.1\mu F$ . There are many factors (board layout, etc) that can affect characteristics. Please verify and confirm using practical applications.

#### 11) Power on reset operation

Please note that the power on reset output varies with the  $V_{DD}$  rise time. Please verify the behavior in the actual operation.

#### 12) Testing on application boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 13) Rush current

When power is first supplied to the IC, rush current may flow instantaneously. It is possible that the charge current to the parasitic capacitance of internal photo diode or the internal logic may be unstable. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

#### 14) C<sub>T</sub> pin discharge

Due to the capabilities of the  $C_T$  pin discharge transistor, the  $C_T$  pin may not completely discharge when a short input pulse is applied, and in this case the delay time may not be controlled. Please verify the actual operation.

15) This IC has extremely high impedance terminals. Small leak current due to the uncleanness of PCB surface might cause unexpected operations. Application values in these conditions should be selected carefully. If  $10M\Omega$  leakage is assumed between the C<sub>T</sub> terminal and the GND terminal,  $1M\Omega$  connection between the CT terminal and the V<sub>DD</sub> terminal would be recommended. Also, if the leakage is assumed between the Vout terminal and the GND terminal, the pull up resistor should be less than 1/10 of the assumed leak resistance. The value of Rct depends on the external resistor that is connected to C<sub>T</sub> terminal, so please consider the delay time that is decided by t × R<sub>CT</sub> × C<sub>CT</sub> changes.

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|---------|----------|------------|----------|
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| CLASSIV | CLASSIII | CLASSⅢ     | CLASSIII |

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